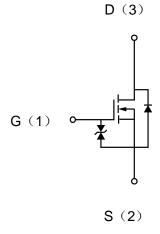




Description

The MOSFET provide the best combination of fast switching, low on-resistance and cost-effectiveness.

MOSFET Product Summary			
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)	
	0.2@ V _{GS} =4.5V		
20	0.25@ V _{GS} =2.5V	±1	
	0.31@ V _{GS} =1.8V		



Absolute maximum rating@25℃

Parameter		Symbol	Value	Units	
Drain-Source Voltage		V _{DS}	20	V	
Gate-Source Voltage		V _{GS}	±8	V	
Continuous Drain	Continuous	I _D	±1	Δ.	
Curren(T _J =150°C)	Pulsed	I _{DP}	±4	А	
Total power dissipation		P _D	140	mW	
Channel temperature		Тсн	150	$^{\circ}$ C	
Range of storage temperature		T _{STG}	-55 to +150	$^{\circ}$	

Thermal resistance

Parameter	Symbol	Limits	Units
Channel to ambient	Rth(ch-a)	800	°C/W

Electrical characteristics per line@25℃(unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Drain-Source Breakdown Voltage	BV _{DSS}	I _D =1mA,V _{GS} =0V	20		-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	$V_{DS} = 0V, V_{GS} = \pm 8V$	-	-	±10	μΑ
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =10V, I _D =1mA	0.5	-	1.1	V
		V _{GS} =4.5V, I _D =650mA	-	0.2	0.25	Ω
Static Drain-Source On-Resistance	R _{DS(ON)}	V _{GS} =2.5V, I _D =450mA	-	0.25	0.3	Ω
		V _{GS} =1.8V, I _D =250mA		0.31	0.45	Ω
Forward transfer admittance	Yfs	V _{DS} =10V, I _D =300mA	395			ms
Input Capacitance	C _{ISS}		-	30		pF
Output Capacitance	Coss	V_{GS} =0V, V_{DS} =10V, f=1MHz	-	13		pF
Reverse Transfer Capacitance	C _{RSS}	1-1101112	-	13		pF
Turn-On Delay Time	t _{d(on)}		-	7		ns
Turn-Off Delay Time	t _{d(off)}	$V_{DD} = 10V, V_{GS} = 4.0V,$	-	23		ns
Turn-On Rise Time	t _r	$R_G=10\Omega, R_L=67\Omega$ $I_D=150mA$	-	15		ns
Turn-On Fall Time	t _f		-	15		ns
Drain-Source Diode Forward Voltage	V _{SD}	V _{GS} =0V,I _S =100mA		-	1.2	V

Typical Characteristics

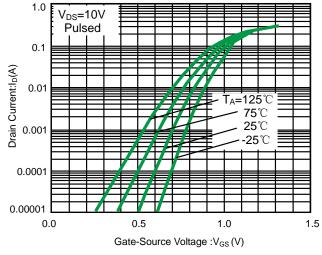


Fig 1. Typical transfer Characteristics

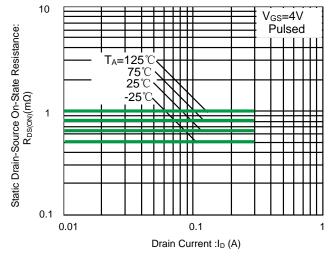


Fig 2. Static drain-source on-state resistance vs. drain current(I)

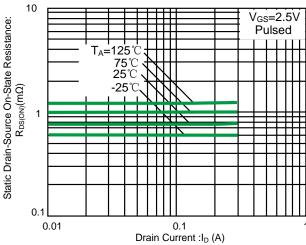


Fig 3. Static drain-source on-state resistance Vs. drain current (\amalg)

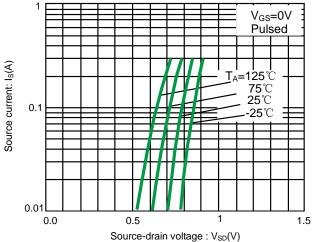


Fig 5. Source current vs. source-drain voltage

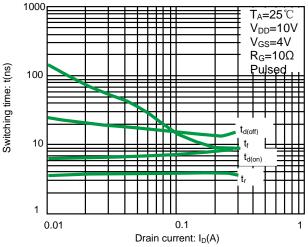


Fig 7. Switching characteristics

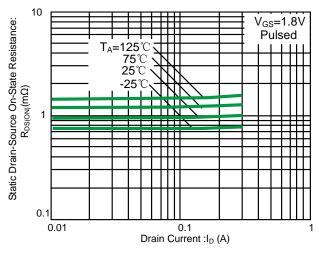


Fig 4. Static drain-source on-state resistance vs. drain current (III)

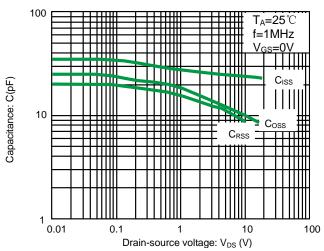


Fig 6. Typical capacitance vs. drain-source voltage

Switching characteristics measurement circuit

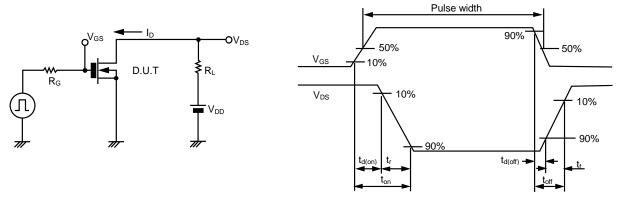
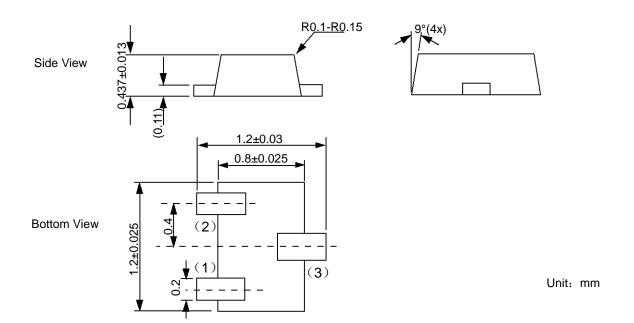
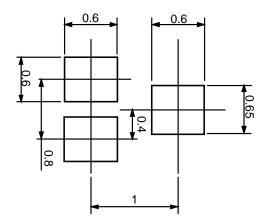


Fig.8 Switching time measurement circuit

Fig.9 Switching time waveforms

Product dimension (SOT-723)





Unit: mm

Ordering information

Device	Package	Shipping		
PNM723T201E0	SOT-723 (Pb-Free)	10000 / Tape & Reel		

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